# NSN 5961-01-563-8168

Transistor - Page 1 of 1



View Online at https://aerobasegroup.com/nsn/5961-01-563-8168

# Inclosure Material:

Ceramic

#### **Overall Length:**

Between 15.8 millimeters and 16.8 millimeters

# **Overall Width:**

Between 25.8 millimeters and 27.6 millimeters

### Internal Configuration:

Junction contact

#### **Internal Junction Configuration:**

Npn

# Semiconductor Material:

Silicon

#### Voltage Rating In Volts Per Characteristic:

60.0 breakdown voltage, collector-to-emitter, with base short-circuited to emitter and 30.0 breakdown voltage, collector-to-emitter, base

open and 4.0 breakdown voltage, emitter-to-base, collector open

#### **Current Rating Per Characteristic:**

2.00 milliamperes zero-gate-voltage source current minor

#### **Power Rating Per Characteristic:**

18.60 watts small-signal input power, common-collector preset

#### Shelf Life:

N/a

#### Unit Of Measure:

---

#### Demilitarization:

No

# Fiig:

A110a0